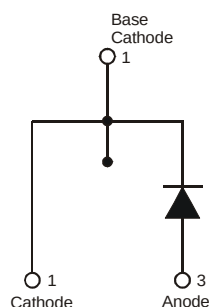


## Features

- DIODESTAR™ is a Proprietary Process for High Voltage Rectifiers which Delivers:
  - Ultra-Fast Reverse Recovery ( $t_{rr} < 30\text{ns}$ ) Giving a Rapid Switching Response
  - Soft Recovery for Low EMI Noise
  - Excellent High Temperature Stability
  - High Forward Surge Capability
- Enables High Efficiency as the Boost Diode in PFC Circuits
- **Lead Free Finish, RoHS Compliant (Note 1)**

## Mechanical Data

- Case: TO-220AC
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 



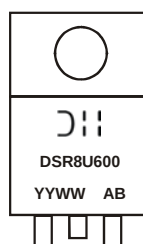
Package Pin Out Configuration

## Ordering Information (Note 2)

| Part Number | Case     | Packaging      |
|-------------|----------|----------------|
| DSR8U600    | TO-220AC | 50 pieces/tube |

- Notes:
1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
  2. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



DSR8U600 = Product Type Marking Code  
 AB = Foundry and Assembly Code  
 YYWW = Date Code Marking  
 YY = Last two digits of year (ex: 10 = 2010)  
 WW = Week (01 - 53)

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

| Characteristic                                                                                   | Symbol           | Value | Unit |
|--------------------------------------------------------------------------------------------------|------------------|-------|------|
| Peak Repetitive Reverse Voltage                                                                  | V <sub>RRM</sub> | 600   | V    |
| Working Peak Reverse Voltage                                                                     | V <sub>RWM</sub> |       |      |
| DC Blocking Voltage                                                                              | V <sub>RM</sub>  |       |      |
| Average Rectified Output Current                                                                 | I <sub>O</sub>   | 8     | A    |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load | I <sub>FSM</sub> | 85    | A    |

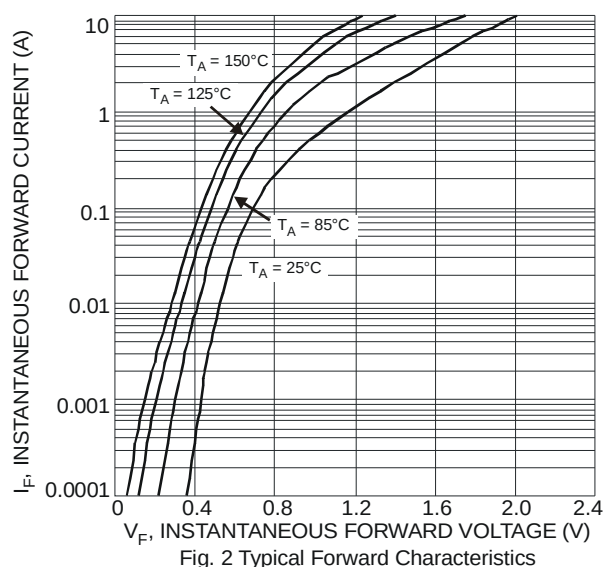
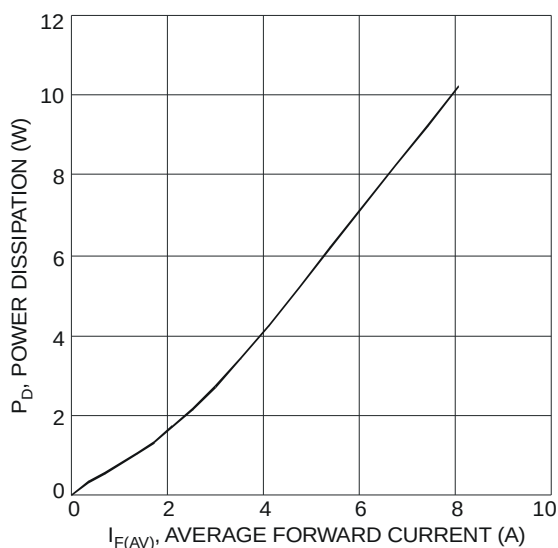
**Thermal Characteristics**

| Characteristic                          | Symbol                            | Value       | Unit |
|-----------------------------------------|-----------------------------------|-------------|------|
| Typical Thermal Resistance (Note 3)     | R <sub>θJC</sub>                  | 2           | °C/W |
| Operating and Storage Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -65 to +175 | °C   |

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic           | Symbol          | Min | Typ | Max | Unit | Test Condition                                                                     |
|--------------------------|-----------------|-----|-----|-----|------|------------------------------------------------------------------------------------|
| Forward Voltage Drop     | V <sub>F</sub>  | -   | -   | 2.5 | V    | I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C                                         |
|                          |                 | -   | 1.3 | 1.8 |      | I <sub>F</sub> = 8A, T <sub>J</sub> = 125°C                                        |
| Leakage Current (Note 4) | I <sub>R</sub>  | -   | -   | 20  | μA   | V <sub>R</sub> = 600V, T <sub>J</sub> = 25°C                                       |
|                          |                 | -   | -   | 200 |      | V <sub>R</sub> = 600V, T <sub>J</sub> = 125°C                                      |
| Reverse Recovery Time    | t <sub>rr</sub> | -   | 23  | 28  | ns   | I <sub>F</sub> = 1A, V <sub>R</sub> = 30V, di/dt = 100A/μs                         |
| Softness Factor          | S               | -   | 1.0 | -   | -    | I <sub>F</sub> = 8A, di/dt = 50A/μs, V <sub>R</sub> = 400V, T <sub>J</sub> = 25°C  |
| Reverse Recovery Current | I <sub>RM</sub> | -   | 1.4 | -   | A    |                                                                                    |
| Reverse Recovery Charges | Q <sub>rr</sub> | -   | 74  | -   | nC   |                                                                                    |
| Softness Factor          | S               | -   | 0.6 | -   | -    | I <sub>F</sub> = 8A, di/dt = 50A/μs, V <sub>R</sub> = 400V, T <sub>J</sub> = 125°C |
| Reverse Recovery Current | I <sub>RM</sub> | -   | 2.5 | -   | A    |                                                                                    |
| Reverse Recovery Charges | Q <sub>rr</sub> | -   | 185 | -   | nC   |                                                                                    |
| Junction Capacitance     | C <sub>J</sub>  | -   | 55  | -   | pF   | 4.0V, 1MHz                                                                         |

Notes: 3. Test with additional heatsink, (Black Aluminum, 45mm\*20mm\*12mm)  
 4. Short duration pulse test used to minimize self-heating effect.



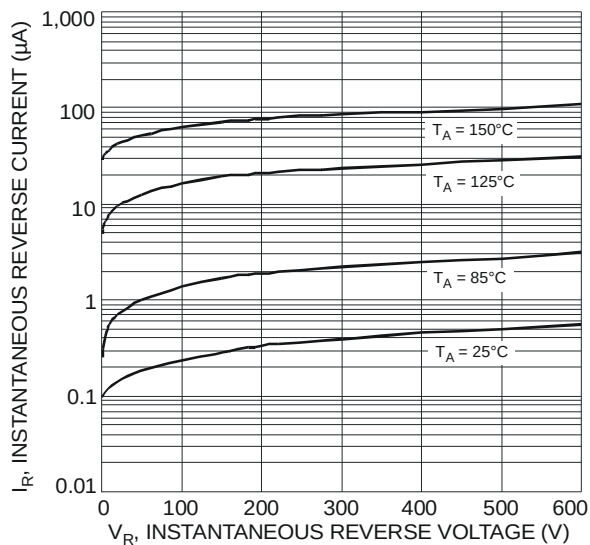


Fig. 3 Typical Reverse Characteristics

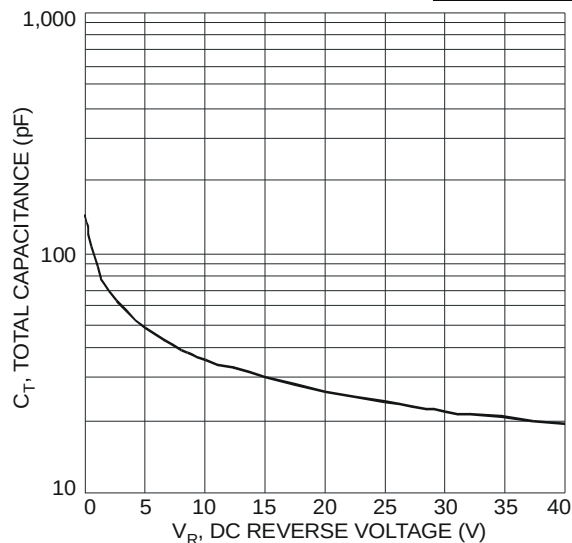


Fig. 4 Total Capacitance vs. Reverse Voltage

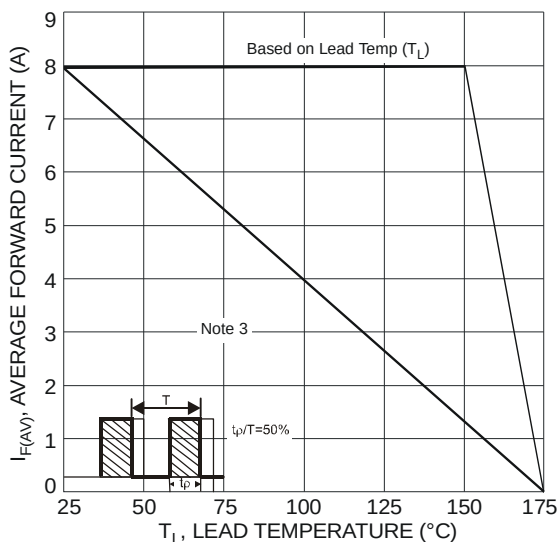


Fig. 5 Forward Current Derating Curve

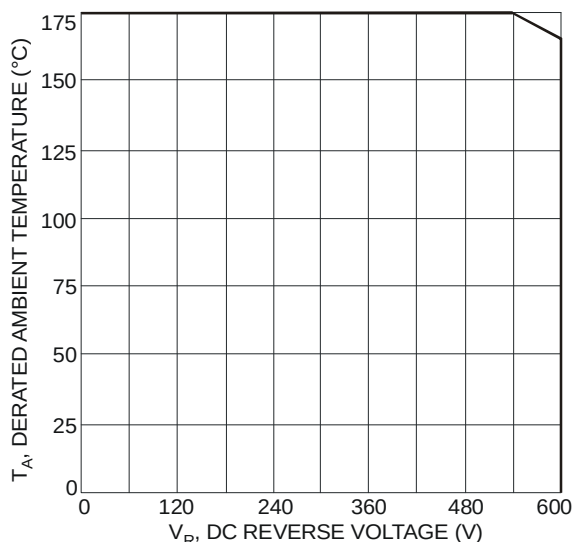
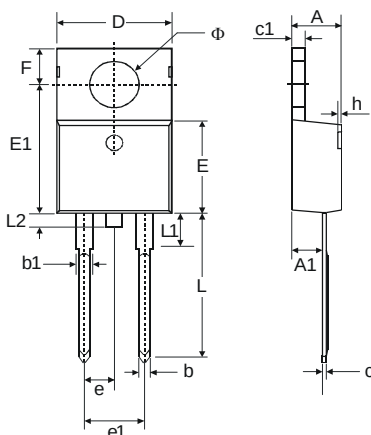


Fig. 6 Operating Temperature Derating

## Package Outline Dimensions



| TO-220AC             |          |       |
|----------------------|----------|-------|
| Dim                  | Min      | Max   |
| A                    | 4.47     | 4.67  |
| A1                   | 2.52     | 2.82  |
| b                    | 0.71     | 0.91  |
| b1                   | 1.17     | 1.37  |
| c                    | 0.31     | 0.53  |
| c1                   | 1.17     | 1.37  |
| D                    | 10.01    | 10.31 |
| E                    | 8.50     | 8.90  |
| E1                   | 12.06    | 12.46 |
| e                    | 2.54 Typ |       |
| e1                   | 4.98     | 5.18  |
| F                    | 2.59     | 2.89  |
| h                    | 0.00     | 0.30  |
| L                    | 13.40    | 13.80 |
| L1                   | 3.56     | 3.96  |
| L2                   | -        | 1.00  |
| Φ                    | 3.735    | 3.935 |
| All Dimensions in mm |          |       |

**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2010, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)